



<a href="#">QN100</a>	MEMORY PRODUCTS QUALITY PROGRAM
<a href="#">QN101</a>	IMPROVED PASSIVATION FOR OTP MEMORY PRODUCTS
<a href="#">QN109</a>	NEW METALISATION SCHEME FOR EPROMS WITH UPGRADED PROCESS
<a href="#">QN110</a>	HIGH RELIABILITY OTP MEMORY PROGRAMMING
<a href="#">QR100</a>	M28F101 1 MEGABIT CMOS/T5 FLASH MEMORY IN PLCC32
<a href="#">QR101</a>	256K & 512K BIT CMOS-E5 OTP ROM IN TSOP28
<a href="#">QR102</a>	M28F101 1 MEGABIT CMOS/T5 FLASH MEMORY IN TSOP32
<a href="#">QR103</a>	ZEROPOWER AND TIMEKEEPER SRAM SURFACE MOUNTED SNAPHAT PACKAGE
<a href="#">QR104</a>	M28F101 1 MEGABIT (128K X 8) CMOS T5-U20 FLASH MEMORY IN PLCC32
<a href="#">QR105</a>	M28F102 1 MEGABIT (64K X 16) CMOS T5 FLASH MEMORY IN TSOP40
<a href="#">QR106</a>	M28F410/420, M28F411/421 4 MEGABIT (X16) AND (X8) FLASH MEMORY IN SO44 AND TSOP40
<a href="#">QR107</a>	M28F102 1 MEGABIT (64K X 16) CMOS T5-U20 FLASH MEMORY IN TSOP40 AND PLCC44
<a href="#">QR108</a>	M28F256 256K (32K X 8) CMOS T5-U20 FLASH MEMORY IN PLCC32
<a href="#">QR109</a>	QUALIFICATION REPORT M28F512 512K (64KX8) CMOS T5-U20 FLASH MEMORY IN PLCC32
<a href="#">QR110</a>	M28F201: 2 MEGABIT (256K X 8) CMOS T6 FLASH MEMORY IN PLCC32
<a href="#">QR111</a>	M28F210/220, 2MBIT (X16) & M28F211/221, 2 MBIT (X8) FLASH MEMORY IN SO44 TSOP48 & TSOP40
<a href="#">QR112</a>	M28F410/420, M28F411/421 T6-U10: 4 MBIT (X16) AND (X8) FLASH MEMORY IN SO44 AND TSOP40

\* To obtain a copy of a document marked with an asterisk, please contact your local Sales Office



- [QRR032](#)                    JANUARY 95 TO DECEMBER 95 - EPROM, FLASH MEMORY,  
EEPROM & SRAM PRODUCTS
- [QRR033](#)                    APRIL 95 TO MARCH 96 - EPROM? FLASH MEMORY,  
EEPROM & SRAM PRODUCTS
- [QRR034](#)                    JULY 1995 TO JUNE 1996 - EPROM,FLASH MEMORY,  
EEPROM AND SRAM PRODUCTS
- [QRR035](#)                    OCTOBER 95 TO SEPTEMBER 96 - EPROM, FLASH  
MEMORY, EEPROM & SRAM